Phase-Cut Dimmable and Active PFC for LED lighting With High Voltage MOSFET Integrated

DESCRIPTION

The TS19830CS is a phase-cut (TRIAC) dimmable constant current control IC with active power factor correction for AC-DC LED lighting control. The TS19830CS is configurable as a non-isolated Buck-Boost converter which integrated 500V power MOSFET. It is compatible with many types of TRIAC dimmers including leading edge and trailing-edge. The IC achieves a high power factor and low total harmonic distortion (THD) and guarantees constant current accuracy to $<\pm 2.5\%$ using Discontinuous Conduction Mode (DCM) operation. TheTS19830CS has built-in protection circuits such as over temperature protection by current degeneration, VCC overvoltage protection and system output open/short circuit protection.

FEATURES

- Phase cut dimmable
- Integrated 500V MOSFET
- Low THD <10%
- Good dimmer compatibility for 120/230V_{AC} Lamps
- Constant Current Accuracy within ±2.5%
- High Power Factor >0.9
- Low BOM Cost Design
- Discontinuous Conduction Mode Control (DCM)
- LED Open Protection
- LED Short protection
- Over Current Protection (OCP)
- Over Thermal Protection (OTP)
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC.
- Halogen-free according to IEC 61249-2-21

APPLICATION

LED lighting

Down lights, Tube lamps, PAR Lamps, Bulbs

ROHS HALOGEN

Pin Definition:

1. VCC	8. GND
2. CS	7. NC
3. COM	6. DRAIN
4. CL	5. DRAIN

Note: MSL 3 (Moisture Sensitivity Level) per J-STD-020

TYPICAL APPLICATION CIRCUIT







TS19830CS Taiwan Semiconductor

ABSOLUTE MAXIMUM RATINGS (Note 1)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Power Supply Pin	V _{cc}	40	V	
CS Voltage to GND	V _{CS}	-0.3 to 5.5	V	
DRAIN Voltage to GND	V _{DRAIN}	-0.3 to 500	V	
CS Voltage to GND	V _{CS}	-0.3 to 5.5	V	
CL Voltage to GND	V _{CL}	-0.3 to 5.5	V	
COM Voltage to GND	V _{COM}	-0.3 to 5.5	V	
Junction Temperature Range	TJ	-40 to +150	°C	
Storage Temperature Range	T _{STG}	-65 to +150	°C	
Lead Temperature (Soldering 10s)	T _{LEAD}	260	°C	
Power Dissipation @ T _A =25 °C	PD	0.6	W	
ESD Rating (Human Body Mode) ^(Note2)	НВМ	2	kV	
ESD Rating (Machine Mode) ^(Note 2)	MM	200	V	

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	LIMIT	UNIT
Thermal Resistance - Junction to Case	R _{eJC}	50	°C/W
Thermal Resistance - Junction to Ambient	R _{eja}	208	°C/W

Note: R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistances. The case thermal reference is defined at the solder mounting surface of the drain pins. R_{BJA} is guaranteed by design while R_{BCA} is determined by the user's board design. R_{0JA} shown below for single device operation on FR-4 PCB in still air. Thermal Resistance is specified with the component mounted on a low effective thermal conductivity test board in free air at $T_A=25^{\circ}C$.

RECOMMENDED OPERATING CONDITIONS (Note 3)					
PARAMETER	SYMBOL	CONDITIONS	UNIT		
Power Supply Pin	V _{cc}	33	V		
CL Voltage to GND	V _{CL}	-0.3 to 0.3	V		
DRAIN Voltage to GND	V _{DRAIN}	-0.3 to 500	V		
CS Voltage to GND	V _{cs}	-0.3 to 5	V		
COM Voltage to GND	V _{COM}	-0.3 to 5	V		
Operating Junction Temperature Range	TJ	-40 to +125	°C		
Operating Ambient Temperature Range	T _{OPA}	-40 to +85	°C		



Taiwan Semiconductor

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNIT
Supply Voltage					•	
Start-up Current	V _{CC(ST)}	V _{CC} = V _{UVLO(on)} -1V		45		μA
Operating Current	I _{OPA}	Operating @ 60kHz		2.1	2.6	mA
UVLO(off)	V _{UVLO(off)}		7	8	9	V
UVLO(on)	V _{UVLO(on)}		16	17.5	19	V
OVP Level on V_{CC} Pin	V _{OVP}		29	31	33	V
Voltage Feedback						
Feedback Reference Voltage	V _{FB}		0.196	0.2	0.204	V
Transconductance	g _m		7	58		μS
Output Sink Current	I _{O-SINK}			5.8		μA
Output Source Current	IO-SOURCE			5.8		μA
Current Sensing		(
Open Loop Voltage	V _{OLP}	CS Pin Open		5		V
Leading-Edge Blanking Time	t _{LEB}			400		ns
Delay to Output	t _{DELAY}			100		ns
Current Limit						
CL Limit Voltage	V _{OCP}			0.3		V
Switching Frequency						
Start Frequency	f _{STR}			4.5		kHz

ELECTRICAL SPECIFICATIONS (V_{cc} = 18V, T_A = 25°C unless otherwise noted)						
PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNIT
MOSFET section						
Drain-Source Breakdown Voltage	BV _{DS}		500			V
Drain-Source On Resistance	R _{DS(ON)}			2.3		Ω
Thermal Section (Note 5,6)						
Thermal Shutdown				150		°C
Thermal Shutdown Release				120		°C

Note:

- Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.
- 2. Devices are ESD sensitive. Handing precaution recommended.
- 3. Thermal Resistance is specified with the component mounted on a low effective thermal conductivity test board in free air at $T_A=25^{\circ}$ C.
- 4. The device is not guaranteed to function outside its operating conditions.

5. Guaranteed by design.

6. Auto Recovery Type.



ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TS19830CS RLG	SOP-8	2,500pcs / 13"Reel

BLOCK DIAGRAM



PIN DESCRIPTION

PIN NO.	NAME	FUNCTION	
1	V _{cc}	Power supply pin for all internal circuitry.	
2	CS 🕺	Input current sense pin.	
3	СОМ	Output pin of error amplifier.	
4	CL	Current limit.	
5.6	DRAIN	High Voltage MOSFET Drain	
7	N/C	No connect	
8	GND	Ground return for all internal circuitry.	



APPLICATION INFORMATION

Start-up Current

The typical start-up current is around 45µA. Very low start-up current allows the PWM controller to increase the value of start-up resistor and then reduce the power dissipation.

UVLO(Under Voltage Lockout)

A hysteresis UVLO comparator is implemented in TS19830. The turn-on and turn-off thresholds level are fixed at 17.5V and 8V respectively. This hysteresis shown in Fig.2 ensures that the start-up capacitor will be adequate to supply the chip during start-up. For quick start-up of the LED driver, the start-up resistor should be matched with the start-up capacitor.



LEB(Leading-Edge Blanking)

Each time the power MOSFET is switched on, a turn-on spike will inevitably occur at the sense resistor. To avoid fault trigger, a 400ns leading-edge blanking time is built in Conventional RC filtering can therefore be omitted. During this blanking period, the current-limit comparator is disabled and cannot switch off the gate driver.

OCP(Over Current Protection)

The TS19830 has built-in cycle by cycle over current protection function on CL pin. As the CL pin voltage is larger than V_{OCP} (0.3V), the gate output will be turned off immediately to avoid the driver board to be burned out.

OVP (Over Voltage Protection) on Vcc

To prevent the LED driver from being damaged, the TS19830 has an implemented OVP function on V_{CC} . When the V_{CC} voltage is higher than the V_{OVP} (31V), the output gate driver circuit will be shut down immediately to stop the switching of power MOSFET. The V_{CC} pin OVP function is an auto recovery type protection. If the OVP condition happens, the pulses will be stopped until the V_{CC} pin voltage is down to the UVLO off level. The TS19830 is working in an auto-recovery mode as shown in Fig. 3.



Fig. 3



19.0

CHARACTERISTICS CURVES

120

120

120



9.0

Figure 5 – V_{REF} vs. Ambient Temperature

Figure 6 – Operating Current vs. Ambient Temperature



PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

TAIWAN SEMICONDUCTOR

9h

SOP-8







Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.